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Research paper

A silver fluoniobate semiconductor with high photo-oxidization abilities and photocatalytic activities



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ABSTRACT

In the past years, nano-sized Nb₂O₅ has been widely as a potential photocatalyst due to its good chemical stability and higher conduction band edge than TiO₂. However, the photocatalytic application of Nb₂O₅ is limited by vide band gap (3.4–4 eV) because only UV light could be harvested. In this work, Nb₂O₅-based photocatalyst, AgNb₂O₅F, was developed by solid-state reaction. The phase formation and surface characteristics were investigated. AgNb₂O₅F has a direct allowed transition with band energy of 2.68 eV. It has a highly positive valence band. The photocatalysis degradation of MB solutions by Nb₂O₅ is less than 10% after the light irradiation ($\lambda > 420$ nm) in 120 min. AgNb₂O₅F shows a rapid degradation, which is 83% under the same conditions. AgNb₂O₅F presents more efficient degradation of organic dyes than Nb₂O₅. This semiconductor also keeps stabilities for photo-corrosions and photo-degradation reactions. The photocatalytic activities were discussed on the luminescence and decay lifetimes.

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1. Introduction

Over the past century, photocatalysis has been widely reported in the promising applications of environmental protecting and water splitting [1–3]. Some oxide semiconductors (e.g. TiO₂, ZnO, and Nb₂O₅ etc) have been paid greats attention for the preparation and photocatalytic properties [4–6]. However, two main drawbacks delay the practical photocatalysis application for the oxide semiconductors. One is the wide band gap which limits its photo-response to only the ultraviolet wavelength region [7] and another is the high electron–hole pair recombination rate in these [8]. Thus, great efforts have been contributed to extend the optical absorption to longer wavelengths [9,10]. Certainly TiO₂ is the most popular candidate under the investigation as a potential photocatalyst.

Among various oxide semiconductors, Nb_2O_5 has good acid character [11], which has been widely reported in many applications such as selective hydrogen (H₂) gas sensor [12], ultra-stable Li storage [13], anode materials for lithium ion batteries [14,15]. As a candidate for photocatalyst [16–19], Nb_2O_5 possesses wide attentions due to its good chemical stability and a higher conduction band (CB) position than TiO₂ [20]. Compared with TiO_2 , Nb_2O_5 presents much delayed charge recombination together with the improved lifetimes of light-induced electrons [21]. This is extremely beneficial for its photocatalysis. However, the bigger energy (3.4–4 eV) of Nb_2O_5 strictly limits its practical application [22].

Efforts have been made to improve photocatalysis of Nb_2O_5 by introducing metal and non-metal dopants [21]. Incorporation of F⁻ions has been regarded to be one of effective methods. F-doping can induce rich defects, which attract migration of light-generated charges from bulk to the surface joining in photocatalysis [23]. However, it is well-known that F⁻-ions in an oxide cannot contribute to neither valence band (VB) nor CB due to its biggest electronegativity (=10.41 eV) [24]. On the contrary F-ions obviously widen band gap and increase band energy [25]. The harvest efficiency for the visible light is still poor.

The purposes of this work are to investigate the photochemical abilities of silver fluoniobate AgNb₂O₅F. The first motivation is that F⁻ions in lattices make covalence strength more rigid. The second consideration is based on the well-known fact: band gap of a semiconductor could be greatly narrowed by the incorporation of Ag-ions in the lattices via hybridization of Ag-4d + O-2p in valence band [26]. In fact, silver niobium photocatalysts have been intensively reported on this reason [27,28]. AgNb₂O₅F was synthesized by developed by solid-state reaction. The phase formation, optical absorption, band structure and photo-degradation effects on methylene blue (MB) were reported.



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2. Experimental

AgNb₂O₅F was synthesized through solid-state reaction. The raw reactants are AgF (99.99%) and Nb₂O₅ (99.9%). In a typical example, 1.269 g AgF and 2.658 g Nb₂O₅ were firstly mixed in an agate mortar with acetone, and then the mixtures were heated at 600 °C for 2 h using an electric furnace in air atmosphere. Secondly, the mixtures were thoroughly ground and then heated in a covered crucible at 800 °C for 2 h. Thirdly the obtained powders were finely ground, which were calcined at 900 °C for 2 h to get the final AgNb₂O₅F products. The single phase formation was confirmed via XRD measurements.

The optical absorption spectra were taken by UV–Vis-NIR spectrophotometer (Cary-5000). The photocatalytic tests were finished by MB degradation of MB solutions (100 mL, 10 mg L⁻¹) with light wavelength $\lambda > 420$ nm. The reactions were finished in a quartz reactor. For a reaction, 0.1 g powders were added in MB solutions. After equilibrium between desorption and adsorption in dark, the photocatalytic experiment was initiated. 3 mL solutions were taken from the reactor after the fixed time period, which were cen-



Fig. 1. XRD pattern of AgNb₂O₅F photocatalyst with standard card.

trifuged to filter the photocatalyst. Then optical absorption of the solutions containing MB was measured to evaluate the photocatalytic effects.

3. Result and discussion

The phase formation was confirmed via XRD measurements as displayed in Fig. 1. The diffraction peaks are in good agreement with the standard card (PDF#32-1017) selected from the database. The sample has a pure crystal phase formation without the any remaining Nb₂O₅ or AgF.

Fig. 2(a) and (b) shows the SEM images of $AgNb_2O_5F$ photocatalyst. It presents the well-developed grains with an average size of 1.65 µm. TEM and HRTEM image in Fig. 2(c) confirm the singlecrystalline property of the particles. The interplanar distance presented on the lattice fringe is about 0.38 nm, which is corresponding to the (3 2 0) preferable growth plane. The elements in the particles were detected via EDS measurements (Fig. 2(d)). The experimental molar ratio of Ag/Nb agrees with the stoichiometric formula.

UV–vis absorption of AgNb₂O₅F is displayed in Fig. 3(a), which exhibits a strong absorption below 460 nm. The steep edge indicates that the absorption is due to the intrinsic band transitions. The absorption confirms that AgNb₂O₅F can efficiently absorb UV–visible light. The band energy (E_g) can be expressed by the formula $\alpha hv \propto (hv - E_g)^k$, where α is optical absorbance, v is incident frequency. k is a constant deciding the transition nature. E_g value of 2.68 eV was obtained at k = 2 by extrapolating the tangent to the Xaxe. AgNb₂O₅F has direct transition with band energy higher than the well-known photocatalysts such as TiO₂ (3.2 eV) [29], ZnO (3.37 eV) [30], Nb₂O₅ (3.4–4 eV) [22].

Optical absorption of niobates is from electron transitions from O^{2-} ligands to Nb^{5+} in NbO_6 . The band gap absorption in Nb_2O_5 follows this discipline. The narrowed band energy in $AgNb_2O_5F$ should be ascribed to the introductions of Ag^+ and F^- ions in the lattices. It is well-known that incorporation of F ions in an oxide cannot contribute to neither the VB nor CB due to its biggest electronegativity (=10.41 eV) [24]. On the contrary F-ions obviously widen band gap and increase band energy of an inorganic



Fig. 2. SEM (a, b), TEM (c), and EDS (d) of AgNb₂O₅F. Inset in (b) and (c) are size distribution and HRTEM image, respectively.

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